



# Operational Amplifiers

## LM101 operational amplifier general description

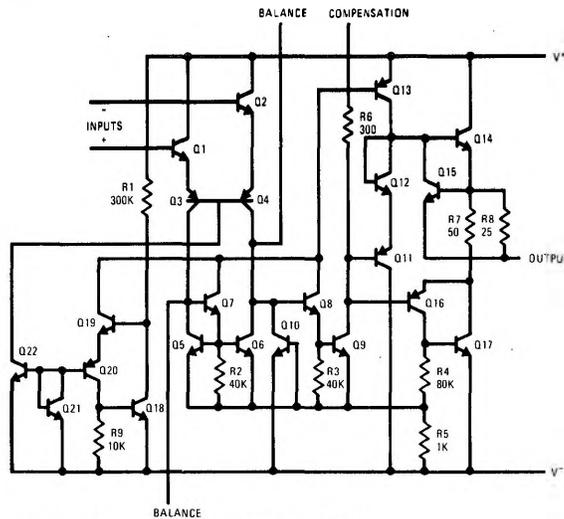
The LM101 is a general-purpose operational amplifier built on a single silicon chip. The resulting close match and tight thermal coupling gives low offsets and temperature drift as well as fast recovery from thermal transients. In addition, the device features:

- Frequency compensation with a single 30 pF capacitor
- Operation from  $\pm 5V$  to  $\pm 20V$
- Low current drain: 1.8 mA at  $\pm 20V$
- Continuous short-circuit protection
- Operation as a comparator with differential inputs as high as  $\pm 30V$

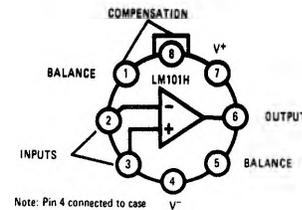
- No latch-up when common mode range is exceeded
- Same pin configuration as the LM709.

The unity-gain compensation specified makes the circuit stable for all feedback configurations, even with capacitive loads. However, it is possible to optimize compensation for best high frequency performance at any gain. As a comparator, the output can be clamped at any desired level to make it compatible with logic circuits. Further, the low power dissipation permits high-voltage operation and simplifies packaging in full-temperature-range systems.

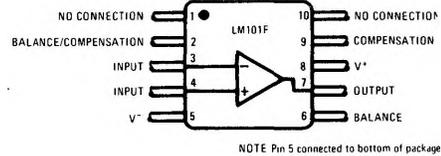
## schematic and connection diagrams



### Metal Can

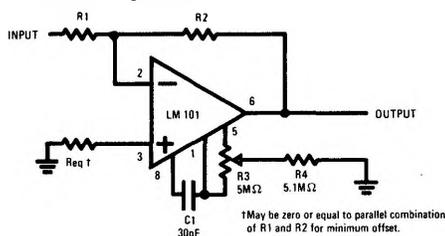


### Flat Package

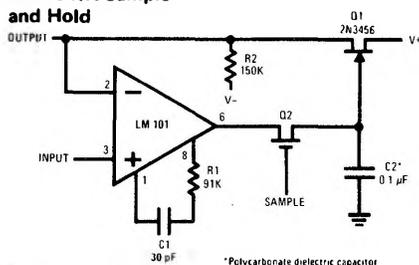


## typical applications \*\*

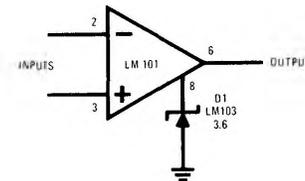
### Inverting Amplifier with Balancing Circuit



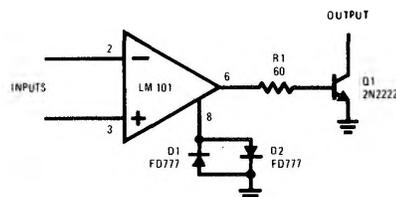
### Low Drift Sample and Hold



### Voltage Comparator for Driving DTL or TTL Integrated Circuits



### Voltage Comparator for Driving RTL Logic or High Current Driver



\*\* Pin connections shown are for the metal can package

**absolute maximum ratings**

Supply Voltage	±22V
Power Dissipation (Note 1)	500 mW
Differential Input Voltage	±30V
Input Voltage (Note 2)	±15V
Output Short-Circuit Duration (Note 3)	Indefinite
Operating Temperature Range	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 60 sec)	300°C

**electrical characteristics** (note 4)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	$T_A = 25^\circ\text{C}$ , $R_S \leq 10\text{k}\Omega$		1.0	5.0	mV
Input Offset Current	$T_A = 25^\circ\text{C}$		40	200	nA
Input Bias Current	$T_A = 25^\circ\text{C}$		120	500	nA
Input Resistance	$T_A = 25^\circ\text{C}$	300	800		k $\Omega$
Supply Current	$T_A = 25^\circ\text{C}$ , $V_S = \pm 20\text{V}$		1.8	3.0	mA
Large Signal Voltage Gain	$T_A = 25^\circ\text{C}$ , $V_S = \pm 15\text{V}$ $V_{\text{OUT}} = \pm 10\text{V}$ , $R_L \geq 2\text{k}\Omega$	50	160		V/mV
Input Offset Voltage	$R_S \leq 10\text{k}\Omega$			6.0	mV
Average Temperature Coefficient of Input Offset Voltage	$R_S \leq 50\Omega$		3.0		$\mu\text{V}/^\circ\text{C}$
	$R_S \leq 10\text{k}\Omega$		6.0		$\mu\text{V}/^\circ\text{C}$
Input Offset Current	$T_A = +125^\circ\text{C}$ $T_A = -55^\circ\text{C}$		10 100	200 500	nA nA
Input Bias Current	$T_A = -55^\circ\text{C}$		0.28	1.5	$\mu\text{A}$
Supply Current	$T_A = +125^\circ\text{C}$ , $V_S = \pm 20\text{V}$		1.2	2.5	mA
Large Signal Voltage Gain	$V_S = \pm 15\text{V}$ , $V_{\text{OUT}} = \pm 10\text{V}$ $R_L \geq 2\text{k}\Omega$	25			V/mV
Output Voltage Swing	$V_S = \pm 15\text{V}$ , $R_L = 10\text{k}\Omega$ $R_L = 2\text{k}\Omega$	±12 ±10	±14 ±13		V V
Input Voltage Range	$V_S = \pm 15\text{V}$	±12			V
Common Mode Rejection Ratio	$R_S \leq 10\text{k}\Omega$	70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 10\text{k}\Omega$	70	90		dB

**Note 1:** For operating at elevated temperatures, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance of 150°C/W junction to ambient or 45°C/W junction to case for the metal-can package. For the flat package, the derating is based on a thermal resistance of 185°C/W when mounted on a 1/16-inch-thick, epoxy-glass board with ten, 0.03-inch-wide, 2-ounce copper conductors (see curve).

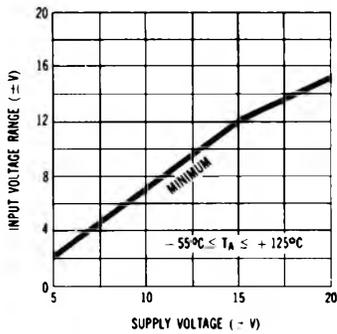
**Note 2:** For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

**Note 3:** Continuous short circuit is allowed for case temperatures to +125°C and ambient temperatures to +70°C.

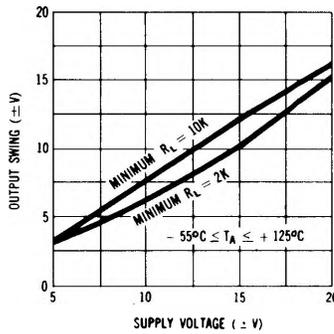
**Note 4:** These specifications apply for  $-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ ,  $\pm 5\text{V} \leq V_S \leq \pm 20\text{V}$  and  $C_1 = 30\text{ pF}$  unless otherwise specified.

guaranteed performance

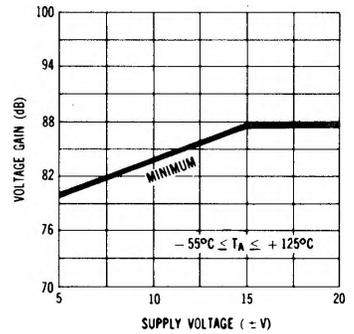
Input Voltage Range



Output Swing

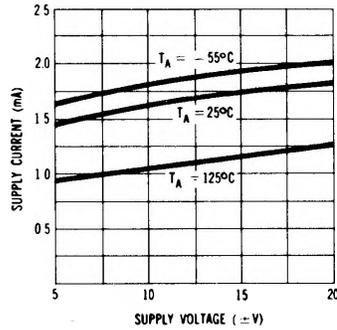


Voltage Gain

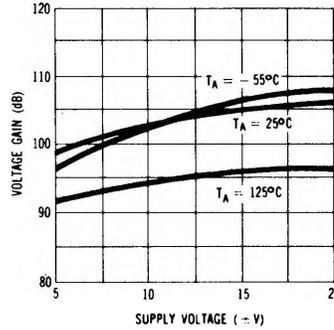


typical performance

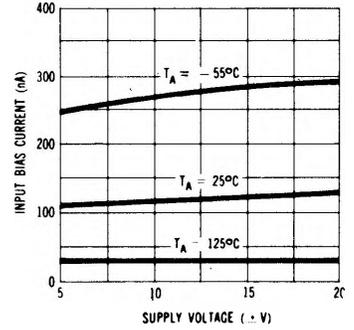
Supply Current



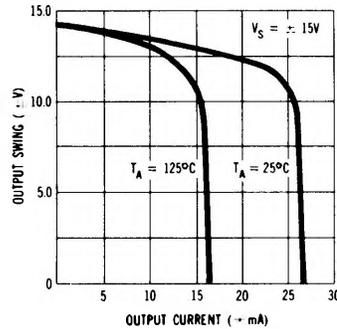
Voltage Gain



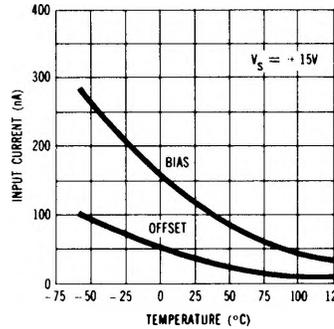
Input Bias Current



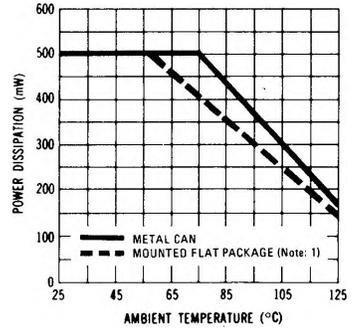
Current Limiting



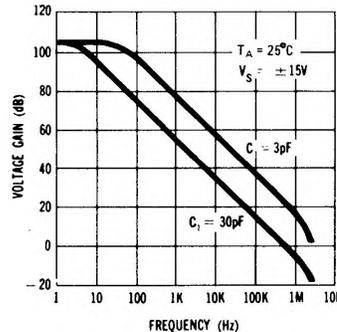
Input Current



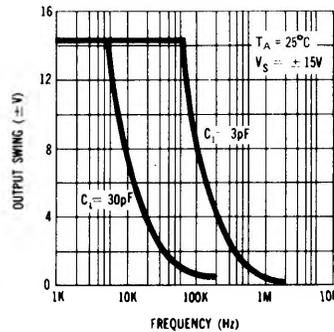
Maximum Power Dissipation



Open Loop Frequency Response



Large Signal Frequency Response



Voltage Follower Pulse Response

